

Dihedral-angle-corrected registry-dependent interlayer potential for multilayer graphene structures

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The structural relaxation of multilayer graphene is essential in describing the interesting electronic properties induced by intentional misalignment of successive layers, including the recently reported superconductivity in twisted bilayer graphene. This is difficult to accomplish without an accurate interatomic potential. Here, we present a new, registry-dependent Kolmogorov-Crespi type interatomic potential to model interlayer interactions in multilayer graphene structures. It consists of two parts representing attractive interaction due to dispersion, and repulsive interaction due to anisotropic overlap of electronic orbitals. An important new feature is a dihedral-angle-dependent term that is added to the repulsive part in order to describe correctly several distinct stacking states that the original Kolmogorov-Crespi potential cannot distinguish. We refer to the new model as the Dihedral-angle-corrected Registry-dependent Interlayer Potential (DRIP). Computations for several test problems show that DRIP correctly reproduces the binding, sliding, and twisting energies and forces obtained from *ab initio* total-energy calculations based on density functional theory. We use the new potential to study the structural properties of a twisted graphene bilayer and the exfoliation of graphene from graphite. Our potential is available through the OpenKIM interatomic potential repository at <https://openkim.org>.

I. INTRODUCTION

Since the discovery of graphene¹, two-dimensional (2D) materials have been shown to possess remarkable electronic, mechanical, thermal, and optical properties with great potential for nanotechnology applications, such as semiconductors, ultrasensitive sensors, and medical devices²⁻⁵. Stacked 2D materials (or “heterostructures”) have even more unusual and novel properties that their monolayer and 3D counterparts do not possess.^{6,7} For example, the electronic band gap of a graphene bilayer can be tuned by applying a variable external electric field, which allows great flexibility in the design and optimization of semiconductor devices such as p-n junctions and transistors.⁸ A different manifestation of interesting behavior not found in the bulk is the recently reported superconductivity in intentionally misaligned (by a relative twist of $\sim 1.1^\circ$) graphene bilayers⁹. As a prototype of a stacked 2D material, multilayer graphene (“graphitic structure” hereafter) exhibits strong sp^2 covalent bonds within layers and weak van der Waals (vdW) and orbital repulsion interactions between layers. Although weak, it is the interlayer interaction that defines the function of nanodevices such as nanobearings, nanomotors and nanoresonators.¹⁰

To simulate the mechanical behavior of graphitic structures it is necessary to model the interactions between

the electrons and the ions, which produce the forces governing atomic motion and deformation. First-principles approaches that involve solving the Schrödinger equation are most accurate, but due to hardware and algorithmic limitations, this approach is typically limited to studying small molecular systems and crystalline materials characterized by compact unit cells with an upper limit on the number of atoms in the range of $\sim 10^3$. Empirical interatomic potentials are computationally far less costly than first-principles methods and can therefore be used to compute static and dynamic properties that are inaccessible to quantum calculations, such as dynamical tribological properties of large-scale graphene interfaces.¹¹⁻¹³

There have been many efforts to produce an interatomic potential that would adequately describe the properties of graphitic structures, in particular the interactions between layers. However, as we argue in detail in this paper, the existing potentials fall short of capturing key elements of the graphitic structures of interest. Therefore, there is a pressing need to construct an accurate interlayer potential that will elucidate many of the important structural properties of these structures.

The paper is structured as follows. In Section II we briefly review the nature of existing interatomic potentials that might be applied to graphitic structures, we explain their shortcomings, and elaborate on the need for constructing a new potential. In Section III, the functional form of the new model is presented, together with a description of the fitting process that determines the values of all the parameters that appear in it. In Section IV, the predictions of the new model for several canonical properties of interest are compared with other potentials

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and results from *ab initio* total energy calculations based on density functional theory (DFT). Large-scale applications of the new model are discussed in Section V. The paper is summarized in Section VI.

II. NEED FOR NEW GRAPHITIC POTENTIAL

A large number of interatomic potentials have been developed to model the strong covalent bonds in carbon systems. Among these are bond-order potentials, such as the Tersoff^{14,15} and REBO^{16,17} potentials, which allow for bond breaking and formation depending on the local atomic environments. Such models have been shown to be accurate for many problems and are widely used, but are not suitable for layered 2D materials since they do not include long-range weak interactions. To address this, the AIREBO¹⁸ potential (based on REBO) added a Lennard-Jones (LJ) potential^{19,20} to model vdW interactions. For graphitic structures, the LJ potential works well in describing the overall binding characteristics between graphene layers. For example, the LJ parameterization used in AIREBO predicts an equilibrium layer distance of 3.354 Å and a *c*-axis elastic modulus of 40 GPa for graphite¹⁸, in good agreement with first-principles and experimental results. The isotropic nature of LJ, that is, the fact that it depends only on distance between atoms and not orientation, makes it too smooth to distinguish energy variations for different relative alignments of layers.²¹ Fig. 1b shows the energy variation obtained by sliding one layer relative to the other along the armchair direction of a graphene bilayer. The energy remains nearly constant with a maximal difference of 0.4 meV/atom between the AA and AB stackings, a small fraction (6%) of the DFT result (also shown in the figure).

The reason that the LJ potential fails to capture the energy variations due to interlayer sliding is that in addition to vdW, the interlayer interactions include short-range Pauli repulsion between overlapping π orbitals of adjacent layers. These repulsive interactions are not well described by a simple pair potential like LJ.^{10,12,13} To account for this registry effect (relative alignment of layers), Kolmogorov and Crespi (KC) developed a registry-dependent interlayer potential for graphitic structures.¹⁰ In the KC potential, the dispersive (vdW) attraction between layers is described using the same theoretically-motivated r^{-6} term as in LJ, and π orbital overlap is modeled by a Morse²² type exponential multiplied by a registry-dependent modifier that depends on the transverse distance between atom pairs. The KC potential has been adapted for other 2D materials such as h-BN¹² and graphene/h-BN^{13,23} heterostructures.

The energy corrugation obtained by the KC potential is in quantitative agreement with DFT (once shifted to account for a different reference energy) as shown in Fig. 1b. However, the forces obtained from the KC potential deviate significantly from the DFT results. This implies that equilibrium structures associated with energy minima will differ as well. To illustrate this point, consider a graphene bilayer where one layer is rigidly rotated relative to the other. Fig. 1c shows the force in the *z*-direction (perpendicular to the layers) acting on the bottom atom on the rotation axis (atom 1 in the bottom layer in Fig. 1a) as a function of rotation angle. The force predicted by the KC potential decreases and then increases from AA ($\pm 60^\circ$) to AB (0°), whereas DFT predicts a monotonic increase from AA to AB. In particular, the KC potential yields the same *z*-force for the AA and AB stackings²⁴, which indicates that the KC potential cannot distinguish the overlapping atoms at the rotation center in these states. This is intrinsic to the KC potential. The force on the central atom in the AA and AB states is identical, regardless of the choice of KC parameters. The LJ potential does even worse (Fig. 1c) predicting a constant force on the central atom that is independent of the rotation angle.

In the present paper, a new registry-dependent interlayer potential for graphitic structures is developed that addresses the limitations of the KC potential described above. A dihedral-angle-dependent term is introduced into the registry modifier of the repulsive part that makes it possible to distinguish forces in AA and AB states. We refer to this potential as the Dihedral-angle-corrected Registry-dependent Interlayer Potential (DRIP). DRIP is validated by showing that it correctly reproduces the DFT energy and forces for different sliding and rotated states as well as structural and elastic properties. It is then applied to study structural relaxation in twisted graphene bilayers and exfoliation of graphene from graphite; these representative examples are large-scale applications that cannot be studied using DFT. The potential has been implemented as a DRIP Model Driver²⁵ and the parameterization in this paper has been implemented as a Model²⁶ at OpenKIM^{27,28}. (See details in Appendix A.)

III. DEFINITION OF NEW MODEL

The DRIP functional form is

$$\mathcal{V} = \frac{1}{2} \sum_{i \in \text{layer 1}} \sum_{j \in \text{layer 2}} (\phi_{ij} + \phi_{ji}), \quad (1)$$

where the pairwise interaction is based on the KC form with dihedral modifications:

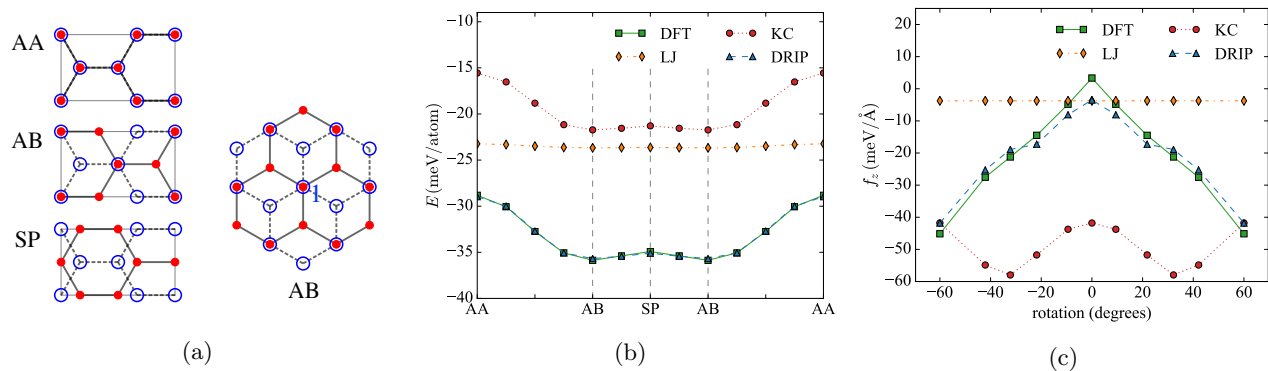


FIG. 1: Energy and force variations when sliding and twisting a graphene bilayer. (a) Schematic representation of high-symmetry graphene bilayer configurations: AA, AB, and saddle point (SP) stacking. (b) Energy variation of sliding one layer relative to the other along the armchair direction. (c) Out-of-plane component of the force on the atom at the rotation center (blue circle labeled 1 in the bottom layer in panel (a)). Rotation by 0° corresponds to AB stacking, and rotation by $\pm 60^\circ$ corresponds to AA stacking. In both sliding and twisting, periodic boundary conditions are applied and the layer separation is fixed at 3.396 Å. Details are provided in Section IV.

$$\phi_{ij} = f_c(x_r) \left[e^{-\lambda(r_{ij}-z_0)} \left[C + f(\rho_{ij}) + g(\rho_{ij}, \{\alpha_{ij}^{(m)}\}) \right] - A \left(\frac{z_0}{r_{ij}} \right)^6 \right], \quad m = 1, 2, 3. \quad (2)$$

The cutoff function $f_c(x)$ is same as that used in the ReaxFF potential²⁹ and the interlayer potential for h-BN^{12,13}:

$$f_c(x) = 20x^7 - 70x^6 + 84x^5 - 35x^4 + 1, \quad (3)$$

for $0 \leq x \leq 1$ and vanishes for $x > 1$, while it has zero first and second derivatives at $x = 1$; in the expressions where this function appears its argument is always non-negative. The variable x_r in Eq. (2) is the scaled pair distance $x_r = r_{ij}/r_{\text{cut}}$. The use of $f_c(x_r)$ ensures that DRIP is smooth at the cutoff r_{cut} , a feature that the KC model does not possess.

The term with r_{ij}^{-6} dependence in Eq. (2) models attractive vdW interactions (as in LJ), while the repulsive interactions due to orbital overlap are modeled by the exponential term multiplied by a registry-dependent modifier. The transverse distance function $f(\rho)$ has the same form as in KC:

$$f(\rho) = e^{-y^2} [C_0 + C_2 y^2 + C_4 y^4], \quad y = \frac{\rho}{\delta} \quad (4)$$

with its argument in Eq. (2) given by the expression

$$\rho_{ij}^2 = r_{ij}^2 - (\mathbf{n}_i \cdot \mathbf{r}_{ij})^2, \quad (5)$$

in which \mathbf{r}_{ij} is the vector connecting atoms i and j , r_{ij} is the corresponding pair distance, and \mathbf{n}_i is the layer normal at atom i . For example, as shown in Fig. 2, \mathbf{n}_i can be defined as the normal to the plane determined by the three nearest-neighbors of atom i : k_1, k_2 and k_3 :

$$\mathbf{n}_i = \frac{\mathbf{r}_{k_1 k_2} \times \mathbf{r}_{k_1 k_3}}{\|\mathbf{r}_{k_1 k_2} \times \mathbf{r}_{k_1 k_3}\|}. \quad (6)$$

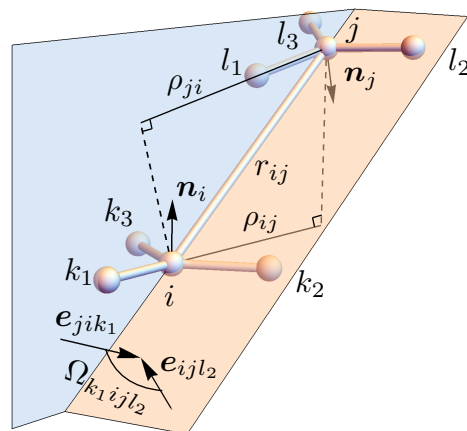


FIG. 2: Schematic representation of an atomic geometry that defines the normal vectors \mathbf{n}_i and \mathbf{n}_j and the dihedral angle $\Omega_{k_1 i j l_2}$.

Note that in general $\rho_{ij} \neq \rho_{ji}$ because the normals \mathbf{n}_i and \mathbf{n}_j depend on their local environments.

The dihedral angle function is given by

$$g(\rho, \{\alpha_{ij}^{(m)}\}) = B f_c(x_\rho) \sum_{m=1}^3 e^{-\eta \alpha_{ij}^{(m)}}, \quad (7)$$

where $\alpha_{ij}^{(m)}$ is the product of the three cosines of the dihedral angles formed by atom i (in layer 1), its m th nearest-neighbor k_m , atom j (in layer 2), and its three

nearest-neighbors l_1, l_2 and l_3 :

$$\alpha_{ij}^{(m)} = \cos \Omega_{k_m i j l_1} \cos \Omega_{k_m i j l_2} \cos \Omega_{k_m i j l_3} \quad (8)$$

$$\cos \Omega_{kijl} = \mathbf{e}_{jik} \cdot \mathbf{e}_{ijl} \quad (9)$$

$$\mathbf{e}_{jik} = \frac{\mathbf{r}_{ik} \times \mathbf{r}_{ji}}{\|\mathbf{r}_{ik} \times \mathbf{r}_{ji}\|}, \quad \mathbf{e}_{ijl} = \frac{\mathbf{r}_{jl} \times \mathbf{r}_{ij}}{\|\mathbf{r}_{jl} \times \mathbf{r}_{ij}\|}. \quad (10)$$

To understand the physical origin of the terms defined in Eqs. (8)–(10), recall that a dihedral angle Ω is the angle between two planes defined by four points that intersect at a line defined by two of them as shown in Fig. 2. Here, the intersection line is defined by atoms i and j . The two planes are then defined by atoms (j, i, k_1) and (i, j, l_2) . The normals to these planes are \mathbf{e}_{jik_1} and \mathbf{e}_{ijl_2} , respectively, defined in Eq. (10), with the corresponding dihedral angle given by Eq. (9). The dihedral product $\alpha_{ij}^{(m)}$ monotonically decreases when twisting a graphene bilayer from AB to AA stacking, and consequently can be utilized to construct a potential function that distinguishes AB and AA stacking and the intermediate stacking states. The cutoff function $f_c(x_\rho)$ in Eq. (7) is the same as that in Eq. (3), and $x_\rho = \rho/\rho_{\text{cut}}$, where we set $\rho_{\text{cut}} = 1.562 \text{ \AA}$ to include only a few of the computationally expensive 4-body dihedral angle interactions. The potential has a total of ten parameters, $C_0, C_2, C_4, C, \delta, \lambda, B, \eta, A$, and z_0 , and two cutoffs r_{cut} and ρ_{cut} .

To determine the values of all the parameters that appear in the DRIP potential, we constructed a training set of energies and forces for graphene bilayers at different separation, sliding, and twisting states. The training set is generated from DFT calculations using the Vienna Ab initio Simulation Package (VASP)^{30,31}. The exchange-correlation energy of the electrons is treated within the generalized gradient approximated (GGA) functional of Perdew, Burke and Ernzerhof (PBE)³².

Standard density functionals such as the local density approximation (LDA) and GGA accurately represent Pauli repulsion in interlayer interactions, but fail to capture vdW forces that result from dynamical correlations between fluctuating charge distributions.³³ To address this limitation, various approximate corrections have been proposed including the D2 method³⁴, the D3 method³⁵, the Tkatchenko and Scheffler (TS) method³⁶, the TS method with iterative Hirshfeld partitioning (TSIHP) method³⁷, the many-body dispersion (MBD) method³⁸, and the dDsC dispersion correction method³⁹. To select a correction for the DRIP training set, we used these dispersion correction methods to perform the following computations: equilibrium layer separation of bilayer graphene (d_{AB}) and graphite (d_{graphite}), c -axis elastic modulus of graphite (C_{33}), and the energy difference between the AA and AB states ($\Delta E_{\text{AA-AB}}$). The results, listed in Table I, were compared with more accurate adiabatic-connection fluctuation-dissipation theory based random-phase-approximation (ACFDT-RPA)

TABLE I: Properties obtained from various DFT vdW corrections compared with accurate ACFDT-RPA results

	d_{AB} (\AA)	d_{graphite} (\AA)	C_{33} (GPa)	$\Delta E_{\text{AA-AB}}$ (meV/atom)
D2	3.248	3.218	39.12	7.2
D3	3.550	3.483	35.04	7.2
TS	3.357	3.329	68.31	7.2
TSIHP	3.396	3.350	64.73	7.1
MBD	3.423	3.398	31.64	7.5
dDsC	3.447	3.410	38.43	7.6
ACFDT-RPA	3.39 ^a	3.34 ^b	36 ^b	-

^a Ref. 40.

^b Ref. 41.

computations, which have been shown to provide very accurate description of vdW interactions^{40,41}. The conclusion from these comparisons is that TSIHP and MBD are generally more accurate than the D2, D3, TS and dDsC methods. TSIHP and MBD give comparable predictions for $\Delta E_{\text{AA-AB}}$, but the former overestimates c -axis elastic modulus of graphite, whereas the latter overestimates layer separations for bilayer graphene and graphite. Since the two methods have comparable accuracy, and TSIHP is computationally less expensive, we chose it as the vdW correction in this work, together with the PBE functional.

Each monolayer of the graphene bilayer is modeled as a slab with in-plane lattice constant $a = 2.46 \text{ \AA}$, and the supercell size in the direction perpendicular to the slab is set to 30 \AA to minimize the interaction between periodic images. The sampling grid in reciprocal space is $20 \times 20 \times 1$, with an energy cutoff of 500 eV. A primitive unit cell of a graphene bilayer consists of four basis atoms. To generate a graphene bilayer with different translational registry, the two atoms in the bottom layer are fixed at fractional positions $\mathbf{b}_1 = (0, 0, 0)$ and $\mathbf{b}_2 = (\frac{1}{3}, \frac{1}{3}, 0)$ relative to the graphene lattice vectors $\mathbf{a}_1, \mathbf{a}_2$, and \mathbf{c} , where \mathbf{c} is perpendicular to the plane defined by \mathbf{a}_1 and \mathbf{a}_2 with length equal to the interlayer distance d . The other two atoms are located at $\mathbf{r}_1 = (p, q, 1)$ and $\mathbf{r}_2 = (p + \frac{1}{3}, q + \frac{1}{3}, 1)$. The two parameters $p \in [0, 1]$ and $q \in [0, 1]$ determine the translational registry. For example, the graphene bilayer is in AA stacking (Fig. 3a) when $p = 0$ and $q = 0$, and in AB stacking (Fig. 3b) when $p = \frac{1}{3}$ and $q = \frac{1}{3}$. Due to the symmetry of the honeycomb lattice, only 1/12 of the area defined by \mathbf{a}_1 and \mathbf{a}_2 needs to be sampled to fully explore all translational registry states (see the shaded region in Fig. 3c). The DRIP training set comprised the seven states indicated in the shaded region of Fig. 3c, specifically $(p, q) = (0, 0), (0, \frac{1}{6}), (0, \frac{2}{6}), (0, \frac{3}{6}), (\frac{1}{6}, \frac{1}{6}), (\frac{1}{6}, \frac{2}{6}), (\frac{2}{6}, \frac{2}{6})$. These states include all the high-symmetry states of interest, including AA, AB, and the saddle point (SP) stacking ($p = 0, q = \frac{3}{6}$). The seven translational registry states are sampled at different layer distances d , varying from 2.596 \AA to 6.196 \AA

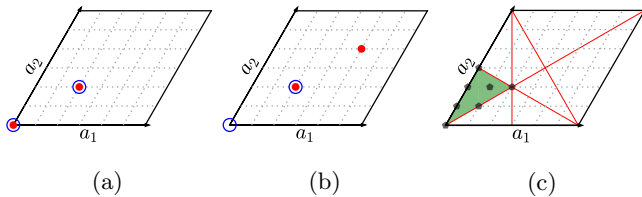


FIG. 3: Primitive unit cell of a graphene bilayer: (a) AA stacking, (b) AB stacking, and (c) unique sampling region and sampling points.

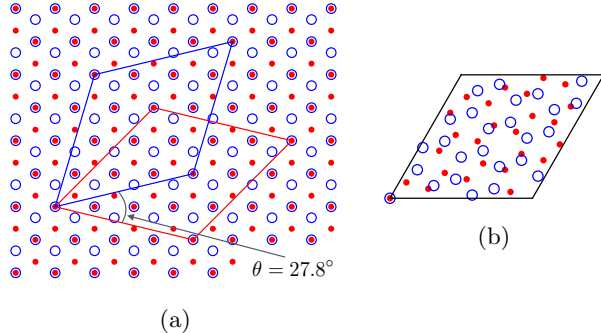


FIG. 4: Example of commensuration of a graphene bilayer. (a) The two layers are commensurate when rotated relative to each other by $\cos^{-1}(\frac{23}{26}) = 27.8^\circ$, which corresponds to $m = 3, n = 7$ according to the condition in Eq. (11). (b) The resulting supercell after rotation, with 26 atoms in each layer.

with a step size of 0.2 \AA . Thus, $7 \times 19 = 133$ translation configurations are included in the training set.

In addition to translation configurations, a set of twisted bilayer configurations are included in the training set. It is possible to construct a commensurate supercell arbitrarily close to any twisting angle according to the commensuration condition^{21,42,43}

$$\theta = \cos^{-1} \left(\frac{3n^2 - m^2}{3n^2 + m^2} \right), \quad (11)$$

where m and n are any two integers satisfying $0 < m < n$. As an example, considering the AB-stacked bilayer in Fig. 4a, a commensurate bilayer can be obtained by rotating one of the layers by $\theta = 27.8^\circ$ ($m = 3, n = 7$) with the supercell shown in Fig. 4b. Four types of twisted bilayers with rotation angles $9.43^\circ, 21.79^\circ, 32.30^\circ$ and 42.10° (corresponding to $(m, n) = (1, 7), (1, 3), (1, 2)$ and $(2, 3)$) are included in the training set. The rotated configurations were evaluated at several separations close to the equilibrium spacing for AB stacking: $d = 3.196, 3.396$ and 3.596 \AA . Thus, $4 \times 3 = 12$ rotated configurations are included in the training set. This does not include rotations for $\theta = 0^\circ$ and $\theta = \pm 60^\circ$ corresponding to the AB and AA stacking states, respectively, which are already included in the training set.

The parameters of the potential are optimized by minimizing a loss function that quantifies the difference between the interatomic potential predictions and the training set. The training set includes M configurations with concatenated coordinates \mathbf{r}_m for $m \in [1, M]$, such that $\mathbf{r}_m \in \mathbb{R}^{3N_m}$ where N_m is the number of atoms in configuration m . The loss function is

$$L(\boldsymbol{\xi}) = \sum_{m=1}^M \frac{1}{2} w_m^e [E_m(\mathbf{r}_m; \boldsymbol{\xi}) - E_m^{\text{DFT}}]^2 + \sum_{m=1}^M \frac{1}{2} w_m^f \|\mathbf{f}(\mathbf{r}_m; \boldsymbol{\xi}) - \mathbf{f}_m^{\text{DFT}}\|^2, \quad (12)$$

where $\boldsymbol{\xi}$ is the set of potential parameters, E_m and $\mathbf{f}(\mathbf{r}_m; \boldsymbol{\xi}) = -(\partial\mathcal{V}/\partial\mathbf{r})|_{\mathbf{r}_m} \in \mathbb{R}^{3N_m}$ are the DRIP potential energy and concatenated forces in configuration m , and w_m^e and w_m^f are the weights associated with the energy and forces of configuration m . For energy in units of eV and forces in units of eV/ \AA , these weights have units of eV^{-2} and $(\text{eV}/\text{\AA})^{-2}$, respectively.

The DFT energy and forces used in the loss function, Eq. (12), E_m^{DFT} and $\mathbf{f}_m^{\text{DFT}}$, require explanation. Since DFT provides only the total energy and forces on atoms due to both intralayer and interlayer interactions it is necessary to separate out the interlayer contributions when constructing the training set. This is accomplished as follows. For configuration m , first the total energy and forces of the bilayer are obtained from DFT: $E_m^{\text{DFT, bilayer}}$, $\mathbf{f}_m^{\text{DFT, bilayer}}$. Then each monolayer is computed separately by removing all atoms from the other monolayer. Thus, there will be two energies, $E_m^{\text{DFT, layer 1}}$ and $E_m^{\text{DFT, layer 2}}$, and two forces, $\mathbf{f}_m^{\text{DFT, layer 1}}$ and $\mathbf{f}_m^{\text{DFT, layer 2}}$ (although each force vector will only contain nonzero components for the atoms belonging to its monolayer). The DFT interlayer energy and forces appearing in Eq. (12) are then defined as:

$$E_m^{\text{DFT}} = E_m^{\text{DFT, bilayer}} - E_m^{\text{DFT, layer 1}} - E_m^{\text{DFT, layer 2}}, \quad (13)$$

$$\mathbf{f}_m^{\text{DFT}} = \mathbf{f}_m^{\text{DFT, bilayer}} - \mathbf{f}_m^{\text{DFT, layer 1}} - \mathbf{f}_m^{\text{DFT, layer 2}}. \quad (14)$$

In the present case, the training set includes $M = 145$ configurations. The forces from all configurations are included in the loss function with unity weights, $w_m^f = 1 (\text{eV}/\text{\AA})^{-2}$ ($m = 1, \dots, 145$). Not all energies are used for training. Only seven translational registry configurations with layer separation at the optimal value, $d = 3.396 \text{ \AA}$, are included to reproduce the minimal binding energy between layers. For these configurations, $w_m^e = 10^6 \text{ eV}^{-2}$ with the remaining energy weights set to zero. Note that the non-zero energy weights w_m^e are deliberately set much larger than the force weights w_m^f , since there are many force components but only one energy associated with a configuration.

The optimization was carried out using the KIM-based Learning-Integrated Fitting Framework (KLIF)⁴⁴

TABLE II: DRIP parameters obtained by minimizing the loss function $L(\xi)$ defined in Eq. (12).

Parameter	Value	Parameter	Value
C_0 (meV)	10.038	B (meV)	16.974
C_2 (meV)	0.0	η (1/Å)	1.1546
C_4 (meV)	80.234	A (meV)	34.797
C (meV)	15.635	z_0 (Å)	3.1223
δ (Å)	0.80615	r_{cut} (Å)	16
λ (1/Å)	3.0506	ρ_{cut} (Å)	1.562

with a geodesic Levenberg-Marquardt minimization algorithm^{45–47}. The objective is to find the set of parameters ξ that minimizes $L(\xi)$. The optimal parameter set identified by this process is listed in Table II.

IV. TESTING OF THE NEW POTENTIAL

We performed an extensive set of calculations to test the ability of DRIP to reproduce its training set (described in Section III), and test its transferability to configurations outside the training set. The calculations using the potential were performed with LAMMPS^{48,49} and DFT calculations with VASP^{30,31}. Periodic boundary conditions are applied in both in-plane directions, and the in-plane lattice constant is fixed at $a = 2.46$ Å. The setup for the DFT computations is the same as that used for generating the training set in Section III.

Fig. 5 shows the unrelaxed forces on the atoms in the bottom layer of the twisted bilayer shown in Fig. 4 (27.8° rotation) with an interlayer distance $d = 3.396$ Å. There are 26 atoms in the bottom layer. For each, the out-of-plane force (z -component) is displayed as a bar. The plot compares the results of LJ, KC and DRIP with DFT. For the LJ potential, the parameterization in the AIREBO potential is used. The DRIP forces are in very good agreement with DFT, whereas the LJ potential yields almost zero forces, and the KC potential greatly overestimates the forces. (Note that the force ranges in the three panels are different). The force on the central atom for DRIP are displayed in Fig. 1c as a function of rotation. The results are in very good agreement with DFT, indicating that the dihedral modification in DRIP successfully addresses the deficiency of the KC potential discussed in Section II.

To investigate the accuracy of the potentials in a dynamical setting, a trajectory is generated using *ab initio* molecular dynamics (AIMD) for the same twisted graphene bilayer discussed above (27.8° degree rotation and 3.396 Å separation) and another with a relative twist of 13.17° and the same separation, both at a temperature of 300 K. For each configuration along the trajectory, the DFT forces due to interlayer interactions are computed using the procedure defined in Eq. (14) and explained above. Next, LAMMPS is used to compute the LJ, KC and DRIP interlayer forces for the AIMD configurations.

The error in the potential forces is shown in Fig. 6. Each dot in the plot represents one atom pulled from one of the configurations along the AIMD trajectory. The horizontal coordinate in the plot is the magnitude of the DFT interlayer force acting on the atom, and the vertical coordinate is the magnitude of the difference between the potential and DFT force vectors for that atom. In the top panel of Fig. 6, the LJ force error increases along the diagonal. This can be understood by considering Fig. 5a where it is seen that the LJ forces are close to zero for all atoms. The LJ forces remain small along the AIMD trajectory since at 300 K the atoms remain close to their equilibrium positions. Thus the force error is proportional to the magnitude of the DFT force as observed. The KC potential exhibits the opposite trend with larger errors at small DFT forces that decrease in average as the magnitude of the DFT force increases. However the spread remains wide. In contrast, the force error for DRIP is smaller than both LJ and KC with a smaller spread, and remains more or less constant across the range of DFT force magnitudes with only a few outliers.

Next, we consider energetics. The interlayer binding energy E_b of a graphene bilayer as a function of layer separation d is shown in Fig. 7 for AB and AA stacking and the twisted configuration shown in Fig. 4. The LJ potential (Fig. 7a) cannot distinguish these states and gives nearly identical binding energy versus layer separation curves for all three. Both KC (Fig. 7b) and DRIP (Fig. 7c) correctly capture the energy differences between the three stacking states, however the KC potential significantly underestimates the depth of the energy wells relative to a reference state of infinite separation, whereas DRIP is in excellent agreement with the DFT results. For all three potentials, the twisted bilayer curve lies between the other two, which is expected since the AB and AA stackings are minimum and maximum energy states. Also notable is that at large separation, the curves for all three stacking states merge since registry effects due to π -orbital overlap become negligible and interactions are dominated by vdW attraction, which are the same for all three states and captured equally well by all three potentials.

A more complete view of the interlayer energetics is obtained by considering the generalized stacking fault energy (GSFE) surface obtained by sliding one layer relative to the other while keeping the layer separation fixed. Fig. 8 shows the results for a layer separation⁵⁰ of $d = 3.196$ Å calculated using DRIP and DFT. DRIP is in quantitative agreement with DFT results. In contrast, the KC GSFE has a similar appearance but with different energy magnitudes and the LJ GSFE is nearly flat. The KC and LJ results are not included for brevity, but the energies of the three potentials along the dashed line in the left plot of Fig. 8 are displayed in Fig. 1b.

As a final test, the following properties are computed: equilibrium spacing for bilayer graphene in the AB and AA stackings, d_{AB} and d_{AA} , the optimal interlayer bind-

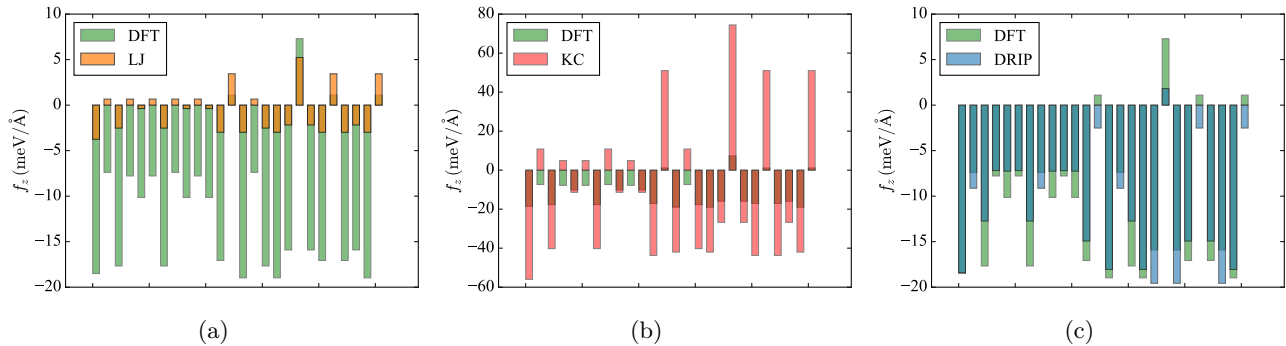


FIG. 5: Out-of-plane component of the forces on the 26 atoms in the bottom layer of the twisted bilayer shown in Fig. 4 (each represented as a bar) computed from DFT and the (a) LJ potential, (b) KC potential, and (c) DRIP model. The layer distance is 3.396 Å.

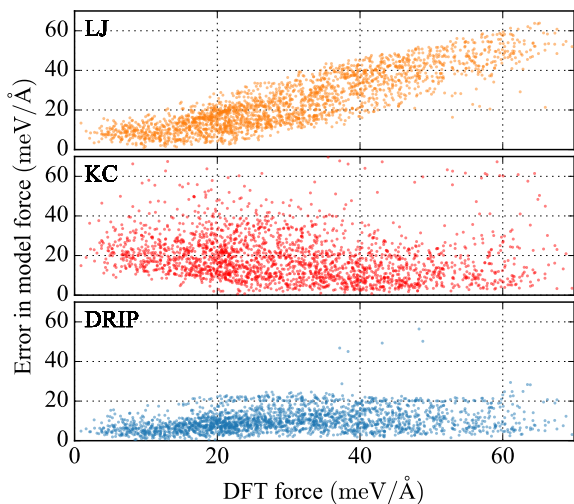


FIG. 6: Deviation of potential forces from DFT results due to interlayer interactions. The configurations are taken from two AIMD trajectories at 300 K.

ing energy for a graphene bilayer (binding energy per atom at the equilibrium spacing for AB stacking), E_{opt} , the equilibrium layer spacing for graphite, d_{graphite} , and the elastic modulus along the c -axis for graphite, C_{33} . These properties are listed in Table III, which also includes results for the LCBOP⁵¹ and AIREBO¹⁸ potentials, accurate first-principles calculations using ACFDT-RPA, and experimental results. The LCBOP potential uses two Morse²² type potentials to model long-range interactions, and the LJ potential^{19,20} is used in the AIREBO potential as discussed in Section I. The properties of the DRIP model are in good agreement with the PBE+TSIHP DFT computations with which the training set was generated. One exception is that the elastic modulus along the c -axis C_{33} is lower, but it is closer to the ACFDT-RPA and experimental results.

TABLE III: The equilibrium separations d_{AB} , d_{AA} of a graphene bilayer in AB and AA stacking, the optimal interlayer binding energy E_{opt} of graphene bilayer, and the equilibrium layer separation d_{graphite} and the elastic modulus along the c -axis C_{33} of graphite computed from the potentials, compared with first-principles and experimental results.

	d_{AB} (Å)	d_{AA} (Å)	E_{opt} (meV/atom)	d_{graphite} (Å)	C_{33} (GPa)
DRIP	3.387	3.551	35.68	3.353	49.44
KC	3.374	3.602	21.58	3.337	36.74
AIREBO	3.392	3.417	22.85	3.354 ^a	40.00 ^a
LCBOP	3.345	3.367	12.51	3.346	32.127
PBE+TSIHP	3.396	3.534	35.87	3.347	64.73
ACFDT-RPA	3.390 ^b	-	-	3.34 ^c	36 ^c
Experiment	-	-	-	3.35 ^d	36.5 ^e , 38.7 ^f

^a Ref. 18.

^b Ref. 40.

^c Ref. 41.

^d Ref. 52.

^e Ref. 53.

^f Ref. 54.

V. APPLICATIONS

To further compare the predictions of the KC potential and DRIP, we carried out two large-scale simulations, beyond the capability of DFT: (1) structural relaxation in a twisted graphene bilayer, and (2) exfoliation of a graphene layer off graphite. In these simulations, the interlayer interactions are modeled using either KC or DRIP, and the REBO¹⁷ potential is used to model the intralayer interactions.

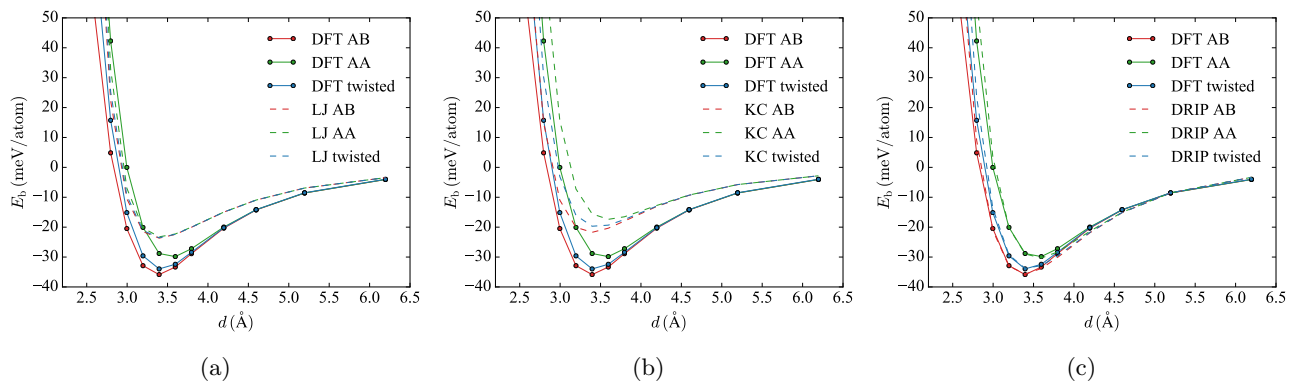


FIG. 7: Interlayer binding energy E_b of a graphene bilayer versus layer separation d for AA stacking, AB stacking, and a twisted bilayer with rotation angle $\theta = 27.8^\circ$ (see Fig. 4) using (a) LJ potential, (b) KC potential, and (c) DRIP model, compared to DFT results.

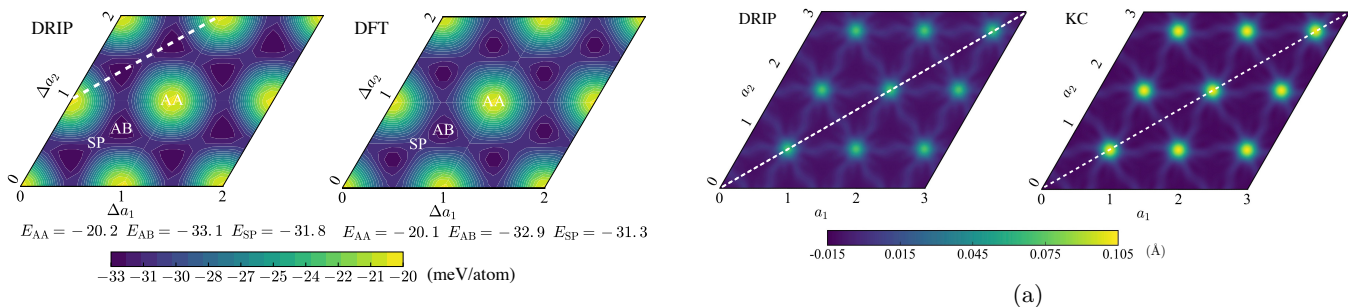


FIG. 8: The GSFE obtained by sliding one layer relative to the other at a fixed layer separation of $d = 3.196$ Å (smaller than the equilibrium separation of 3.396 Å).

On the left are the DRIP model results, and on the right, the DFT results. The sliding parameters Δa_1 and Δa_2 are in units of lattice constant $a = 2.46$ Å.

A. Structural relaxation of a twisted graphene bilayer

The electronic properties of stacked 2D materials can be manipulated by controlling the relative rotation between the layers, which in turn leads to different structural relaxation. A prototypical problem is the twisting of a graphene bilayer. The bilayer is created by rotating one layer relative to the other by $\theta = 0.82^\circ$, setting $(m, n) = (1, 81)$ as discussed in Section III. The out-of-plane relaxation δ of an atom is obtained by subtracting the mean out-of-plane coordinates of all atoms in the top layer from the out-of-plane coordinate of that atom:

$$\delta_i = z_i - \frac{1}{N} \sum_{j=1}^N z_j \quad (15)$$

where z_i is the out-of-plane coordinate of atom i in the top layer and $N = 9842$ is the number of atoms in the top layer⁵⁵.

The out-of-plane relaxation of the twisted bilayer is plotted in Fig. 9. The results of the DRIP and KC mod-

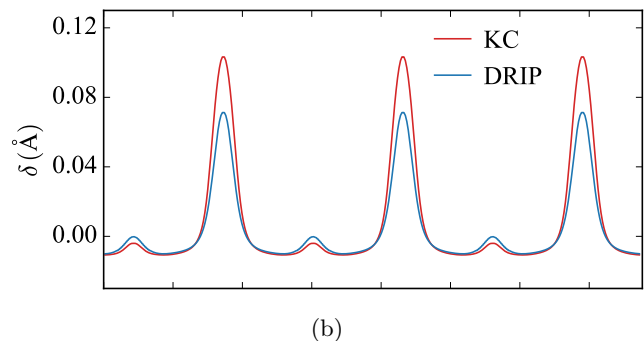


FIG. 9: Out-of-plane relaxation in a twisted bilayer with a relative rotation of $\theta = 0.82^\circ$. (a) Contour plot obtained from the DRIP model and the KC potential, and (b) relaxation along the diagonal indicated by the dashed line in panel (a). The bilayer shown in the figure corresponds to 3×3 supercells used in the computation.

els are qualitatively similar. The bright spots correspond to high-energy AA stacking, the long narrow ribbons correspond to SP stacking, and the triangular regions correspond to alternating AB and BA stacking. It has been shown that the formation of this structure is due to local rotation at AA domains.⁵⁶ Quantitatively, however, the two potentials give different out-of-plane relaxation, especially at the peaks as seen in Fig. 9b. The peak value predicted by DRIP is 0.071 Å, which is 31% smaller than

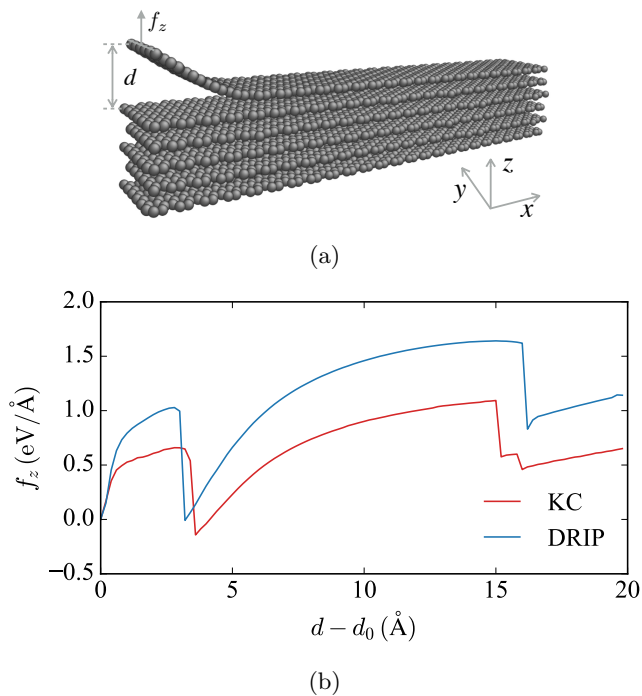


FIG. 10: (a) Schematic demonstrating the process of peeling a graphene layer off graphite, and (b) the normal force, f_z , needed to peel the top layer as a function of the displacement at the left end of the top layer, $d - d_0$. The armchair direction of graphite is aligned with the x -axis. The interlayer distance is $d_0 = 3.35$ Å.

the KC potential value of 0.103 Å. This difference at the peaks could lead to significant differences in electronic properties because twisted graphene bilayers develop highly-localized states around AA-stacked regions for small twist angles⁵⁷.

B. Exfoliation of graphene from graphite

Graphene can be prepared by exfoliating graphite. In this process, the vdW attraction between layers is overcome by peeling a single layer off a graphite crystal. A method as simple as sticking scotch tape to graphite and applying an upward force can be used.¹ To simulate this process, one edge of the top layer of a graphite crystal is pulled up under displacement control conditions as illustrated in Fig. 10a. The atoms at the left end of the top layer are displaced in the z -direction according to $d = d_0 + 0.2k$, where $d_0 = 3.35$ Å is the initial layer separation, and $k = 0, 1, \dots, 99$ is the step number. At each step k , once the displacement is applied to the left atoms, the remaining atoms in the top layer are relaxed. The substrate (bottom 5 layers) is kept rigid during this process. The system contains 600 atoms in each layer of size 105.83 Å and 14.76 Å in the x and y directions,

respectively. The system is periodic in the y direction, and non-periodic the other two directions.

The normal force, f_z , needed to pull the left end of the top layer is plotted in Fig. 10b. Both the KC and DRIP models give qualitatively similar results. The force first increases as the left end is pulled up and then exhibits a sudden drop at about 3 Å. The normal force has two contributions: a) interlayer interactions with atoms in the substrate; and b) covalent-bonded interactions with other atoms in the top layer. The former is almost unchanged before and after the load drop, therefore the drop is mainly due to the in-plane interactions in the top layer. Before the load drop, the right-end of the top layer is trapped in a local minimum created by the substrate (similar to the one denoted as AB in Fig. 8, although there we only consider a graphene bilayer), and consequently as the left end is pulled up, the top layer experiences an increasing axial strain. At about 3 Å, the right-end of the top layer snaps into an adjacent local minimum by moving in the negative x direction (see Supporting Information for a movie showing the snap-throughs associated with the load drop). As a result, the axial strain in the top layer is released and the load is reduced. The same explanation applies to the load drop at a displacement of about 16 Å, and it is expected to continue to occur periodically with continued pulling.

As for the results in Section V A, KC and DRIP are in qualitative agreement, but there are significant quantitative differences. The KC potential predicts an initial peeling load of about 0.5 eV/Å, which is about 50% of the 1.0 eV/Å value predicted by DRIP.

VI. SUMMARY

The interlayer interactions in stacked 2D materials play an important role in determining the functionality of many nanodevices. For graphitic structures, the two-body pairwise LJ potential is too smooth to model the energy corrugation in different stacking states. The registry-dependent KC potential improves on this and correctly captures the energy variation, but fails to yield reasonable forces. In particular, the KC model does not distinguish forces on atoms in the AA and AB stacking states that are different in DFT calculations. The KC model is also discontinuous at the cutoff, which can lead to difficulties in energy minimization and loss of energy conservation in dynamic applications.

To address these limitations, we developed a new potential for graphitic structures based on the KC model. The Dihedral-angle-corrected Registry-dependent Interlayer Potential (DRIP) has a smooth cutoff and includes a dihedral-angle-dependent term to distinguish different stacking states and obtain accurate forces. The potential parameters were determined by training on a set of energies and forces for a graphene bilayer at different separation, sliding and twisting, computed using GGA-DFT calculations, augmented with the Tkatchenko and

Scheffler³⁶ dispersion correction with iterative Hirshfeld partitioning³⁷ to account for the long-range vdW interactions.

To test the quality of the potential, we employed it to compute energetics, forces, and structural and elastic properties for a graphene bilayer in different states. The validation tests show that compared with first-principles results:

1. DRIP correctly predicts the equilibrium layer separation, interlayer binding energy, and generalized stacking fault energy of a graphene bilayer, as well as the equilibrium layer separation of graphite.
2. The *c*-axis elastic modulus C_{33} of graphite is overestimated by DRIP by about 40% relative to ACFDT-RPA and experimental results. However this result is better than PBE+TSIHP (to which DRIP was fit), which overestimates the ACFDT-RPA by 80%.
3. DRIP provides more accurate forces than the KC model across the entire range of bilayer rotations and in particular distinguishes the forces in the AA and AB states that the KC potential cannot.

In two large-scale applications, not amenable to DFT calculations, we showed that DRIP and the KC potential agree qualitatively, but differ quantitatively by 30% in the the out-of-plane relaxation of a twisted graphene bilayer, and by 50% in the normal force required to peel one graphene layer off graphite.

The added four-body dihedral-angle-dependent correction in DRIP is very short-ranged ($\rho_{\text{cut}} = 1.562 \text{ \AA}$) and therefore the computational overhead relative to KC is small. In fact, for the large-scale applications (bilayer relaxation and peeling) described in Section V, DRIP was actually faster than the KC potential in terms of the overall computation time due to improved convergence.

Although DRIP was parameterized against a training set consisting of graphene bilayers, it can be used to describe interlayer interactions for other systems such as graphite and multi-walled carbon nanotubes where the carbon atoms are arranged in layers. This potential only provides a description of the interlayer interactions, and therefore must be used together with a companion model that provides the intralayer interactions, such as the Tersoff^{14,15} or REBO^{16,17} potentials. The DRIP functional form and associated carbon parameterization are archived in the OpenKIM repository²⁵⁻²⁷ at <https://openkim.org>. They can be used with any KIM-compliant molecular simulation code, see Appendix A for details.

```
pair_style kim LAMMPSvirial DRIP_WenTadmor_2018_C__M0_070247075036_000
pair_coeff * * C
```

To use it together with another potential for the in-

ACKNOWLEDGMENTS

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Appendix A: Using the Open Knowledgebase of Interatomic Models (OpenKIM)

The Open Knowledgebase of Interatomic Models (OpenKIM) (<https://openkim.org>) is an open-source, publicly accessible repository of classical interatomic potentials, as well as their predictions for material properties that can be visualized and compared with first-principles data. Interatomic potentials stored in OpenKIM that are compatible with the KIM application programming interface (API) are called “KIM Models.” KIM Models will work seamlessly with a variety of major simulation codes that are compatible with this standard including LAMMPS^{48,49}, ASE^{58,59}, DL_POLY⁶⁰, and GULP^{61,62}.

As an example, we describe how a KIM Model would be used with LAMMPS. In LAMMPS, reactive interatomic potentials are specified using the `pair_style` command. LAMMPS has a “`pair_style kim`” option for using KIM Models. To use KIM Models with LAMMPS, perform the following steps:

1. Install the KIM API (see instructions at <https://openkim.org/kim-api/>);
2. Download and install the desired potential from <https://openkim.org/> (see instructions that come with the API);
3. Enable KIM Models in LAMMPS by typing: “`make yes-kim`” and then compiling LAMMPS.

In a LAMMPS input script, a KIM Model is then selected in the same way as other LAMMPS potentials. For example, the potential developed in this paper can be used with the following two commands:

tralayer interactions, such as Tersoff^{14,15} or REBO^{16,17},

use the LAMMPS “`pair_style hybrid/overlay`” command (see the LAMMPS manual for details).

The advantage of releasing a potential as a KIM Model (as opposed to just a file compatible with LAMMPS or another code), is that it will work with not just LAMMPS, but other major codes as noted above. In addition, a KIM Model has a “KIM ID” that can be cited in publications. The KIM ID provides a unique permanent link to the archived content and includes a three-digit version number to track changes. For example, a modification to the model parameters would lead to a version upgrade (or a new forked model if appropriate). Citing a KIM ID in a publication makes it possible for the reader to download the exact potential used in the reported simulation and to reproduce the results.

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